**Pb Free Product** 



## NCE P-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE4435 uses advanced trench technology to provide excellent R<sub>DS(ON)</sub>, low gate charge and operation with gate voltages as low as 4.5V.

#### **General Features**

•  $V_{DS} = -30V, I_{D} = -9.1A$ 

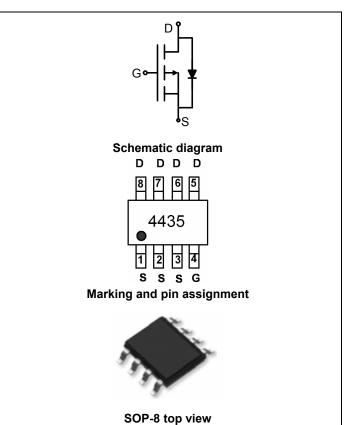
 $R_{DS(ON)}$  < 35m $\Omega$  @  $V_{GS}$ =-4.5V

 $R_{DS(ON)}$  < 20m $\Omega$  @  $V_{GS}$ =-10V

- High power and current handing capability
- Lead free product is acquired
- Surface mount package

#### **Application**

- Battery Switch
- Load switch
- Power management



#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	age Reel Size Tape width		Quantity
4435	NCE4435	SOP-8	Ø330mm	12mm	2500 units

#### Absolute Maximum Ratings (T<sub>A</sub>=25℃unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	-30	V	
Gate-Source Voltage		V <sub>G</sub> S	±20	V	
	T <sub>C</sub> =25°C		-11		
Continuous Desir Courset (T450°C)	T <sub>C</sub> =70°C	I <sub>D</sub>	-9		
Continuous Drain Current (T <sub>J</sub> =150°C)	T <sub>A</sub> =25°C		-9.1	A	
	T <sub>A</sub> =70°C		-7.2		
Drain Current-Pulsed (Note 1)		I <sub>DM</sub>	-50	А	
Maximum Power Dissipation		P <sub>D</sub>	3.1	W	
Operating Junction and Storage Temperatu	re Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}\!\mathbb{C}$	

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	40	°C/W
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### **Electrical Characteristics (T<sub>A</sub>=25 ℃ unless otherwise noted)**



# NCE4435

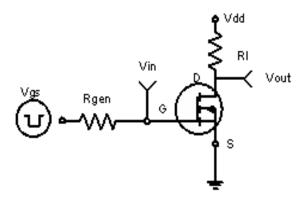
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•	•		•
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-30	-33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V,V <sub>GS</sub> =0V	-	-	-1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics (Note 3)	<u>.                                      </u>		•	•		•
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250\mu A$	-1	-1.5	-3	V
Data Caraca Caraca Data Data Caraca	-	V <sub>GS</sub> =-10V, I <sub>D</sub> =-9.1A	-	16	20	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-6.9A	-	21	35	mΩ
Forward Transconductance	<b>9</b> FS	V <sub>DS</sub> =-15V,I <sub>D</sub> =-9.1A	10	-	-	S
Dynamic Characteristics (Note4)			•	·		I.
Input Capacitance	C <sub>lss</sub>	\/ 45\/\/ 0\/	-	1600	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =-15V, $V_{GS}$ =0V, F=1.0MHz	-	350	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0Wnz	-	300	-	PF
Switching Characteristics (Note 4)	<u>.                                      </u>		•	•		•
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	-	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =-15V, ID=-1A,	-	15	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-10 $V$ , $R_{GEN}$ =6 $\Omega$	-	110	-	nS
Turn-Off Fall Time	t <sub>f</sub>			70	-	nS
Total Gate Charge	Qg	\/ - 45\/   - 0.40	-	30	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-15V,I <sub>D</sub> =-9.1A	-	5.5	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-10V	-	8	-	nC
Drain-Source Diode Characteristics				•		•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-2.1A	-	-	-1.2	V
				•		

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



# **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 

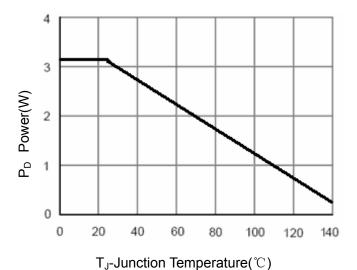
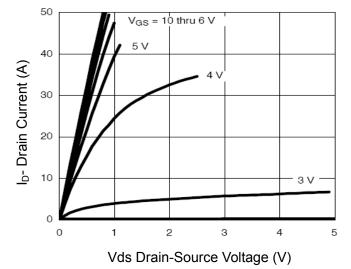


Figure 3 Power Dissipation



**Figure 5 Output Characteristics** 

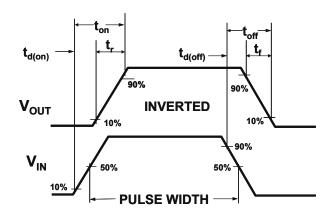
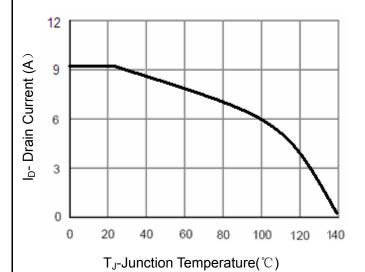


Figure 2:Switching Waveforms



**Figure 4 Drain Current** 

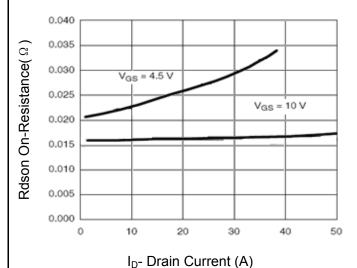
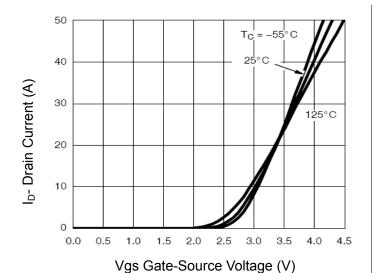
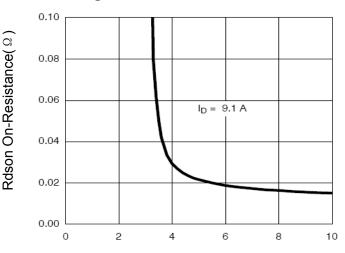


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V)

Figure 9 Rdson vs Vgs

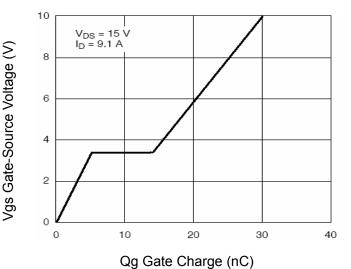


Figure 11 Gate Charge

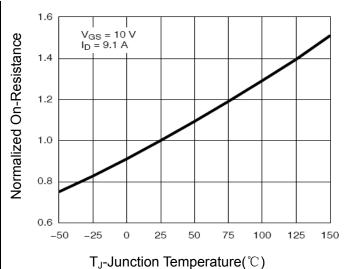
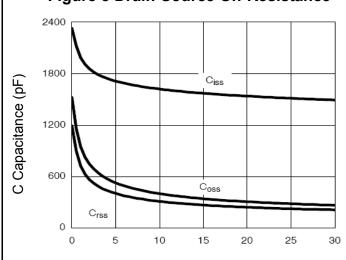


Figure 8 Drain-Source On-Resistance



Vds Drain-Source Voltage (V)

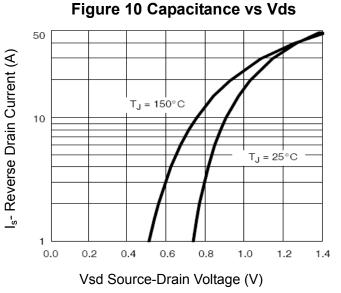
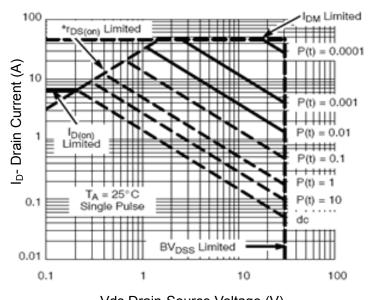


Figure 12 Source- Drain Diode Forward





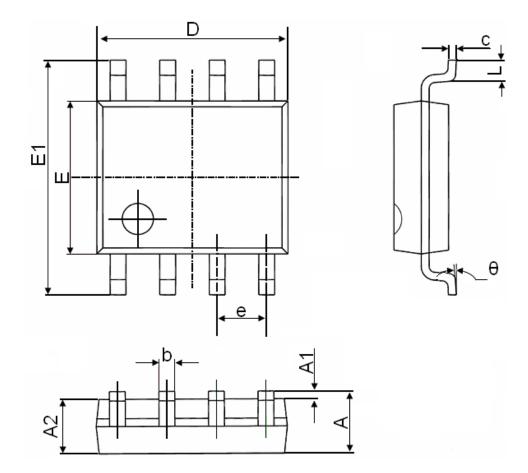
Vds Drain-Source Voltage (V)

**Figure 13 Safe Operation Area** Transient Thermal Impedance r(t), Normalized Effective Duty Cycle = 0.5 0.2 0.1 0.05 1. Duty Cycle, D =  $\frac{t_1}{t_2}$ 2. Per Unit Base =  $R_{thJA}$ 0.02 3.  $T_{JM} - T_A = P_{DM}Z_{thJA}(t)$ 4. Surface Mounted 0.01 10-2 10-4 10-3 10<sup>-1</sup> 10 100 600 Square Wave Pluse Duration(sec)

Figure 14 Normalized Maximum Transient Thermal Impedance



# **SOP-8 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min. Max. Min	Min.	Max.		
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
Е	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	(BSC)	0.050	(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



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